

SILICON NPN RF TRANSISTOR



Central semiconductor Corp.

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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N5109 is a silicon NPN epitaxial planar RF transistor mounted in a hermetically sealed package designed for high frequency amplifier applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (T_A=25°C unless otherwise noted)

	SYMBOL		UNITS					
Collector-Base Voltage	V _{CBO}	40	V					
Collector-Emitter Voltage	VCEO	20	V					
Emitter-Base Voltage	V _{EBO}	3.0	V					
Continuous Collector Current	IC	400	mA					
Continuous Base Current	۱ _B	400	mA					
Power Dissipation	PD	1.0	W					
Power Dissipation (T _C =75°C)	PD	2.5	W					
Operating and Storage Junction Temperature	TJ, Tstg	-65 to +200	°C					

ELECTRICAL CHARACTERISTICS: (T_A=25°C unless otherwise noted)

TEST CONDITIONS	MIN	TYP	MAX	UNITS
V _{CE} =35V, V _{BE} =1.5V			5.0	mA
V _{CE} =15V, V _{BE} =1.5V, T _C =150°C			5.0	mA
V _{CE} =15V			20	μA
V _{EB} =3.0V			100	μA
I _C =0.1mA	40			V
I _C =5.0mA, R _{BE} =10Ω	40			V
I _C =5.0mA	20			V
I _C =100mA, I _B =10mA			0.5	V
V _{CE} =15V, I _C =50mA	40		210	
V _{CE} =5.0V, I _C =360mA	5.0			
V _{CE} =15V, I _C =50mA, f=200MHz	1200			MHz
V _{CB} =15V, I _E =0, f=1.0MHz			3.5	pF
V _{CE} =15V, I _C =10mA, f=200MHz		3.0		dB
V _{CE} =15V, I _C =50mA, f=200MHz	11			dB
	$\label{eq:VCE} \begin{split} &V_{CE} = 35V, V_{BE} = 1.5V \\ &V_{CE} = 15V, V_{BE} = 1.5V, T_{C} = 150^{\circ}\text{C} \\ &V_{CE} = 15V \\ &V_{EB} = 3.0V \\ &I_{C} = 0.1\text{mA} \\ &I_{C} = 5.0\text{mA}, R_{BE} = 10\Omega \\ &I_{C} = 5.0\text{mA}, R_{BE} = 10\Omega \\ &I_{C} = 5.0\text{mA}, I_{B} = 10\text{mA} \\ &V_{CE} = 15V, I_{C} = 50\text{mA} \\ &V_{CE} = 15V, I_{C} = 50\text{mA} \\ &V_{CE} = 15V, I_{C} = 50\text{mA}, f = 200\text{MHz} \\ &V_{CB} = 15V, I_{E} = 0, f = 1.0\text{MHz} \\ &V_{CE} = 15V, I_{C} = 10\text{mA}, f = 200\text{MHz} \end{split}$	$\begin{array}{ll} V_{CE} = 35V, V_{BE} = 1.5V \\ V_{CE} = 15V, V_{BE} = 1.5V, T_{C} = 150^{\circ}\text{C} \\ V_{CE} = 15V \\ V_{EB} = 3.0V \\ I_{C} = 0.1\text{mA} & 40 \\ I_{C} = 5.0\text{mA}, R_{BE} = 10\Omega & 40 \\ I_{C} = 5.0\text{mA} & 20 \\ I_{C} = 100\text{mA}, I_{B} = 10\text{mA} \\ V_{CE} = 15V, I_{C} = 50\text{mA} & 40 \\ V_{CE} = 15V, I_{C} = 50\text{mA} & 5.0 \\ V_{CE} = 15V, I_{C} = 50\text{mA}, f = 200\text{MHz} \\ V_{CB} = 15V, I_{E} = 0, f = 1.0\text{MHz} \\ V_{CE} = 15V, I_{C} = 10\text{mA}, f = 200\text{MHz} \end{array}$	$\begin{array}{llllllllllllllllllllllllllllllllllll$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$

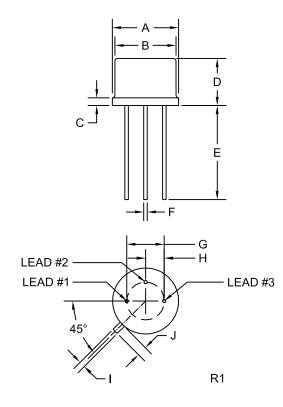
R5 (4-February 2016)



2N5109

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TO-39 CASE - MECHANICAL OUTLINE



DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
A (DIA)	0.335	0.370	8.51	9.40		
B (DIA)	0.315	0.335	8.00	8.51		
С	-	0.040	-	1.02		
D	0.240	0.260	6.10	6.60		
E	0.500	-	12.70	-		
F (DIA)	0.016	0.021	0.41	0.53		
G (DIA)	0.200		5.08			
Н	0.100		2.54			
	0.028	0.034	0.71	0.86		
J	0.029	0.045	0.74	1.14		
TO-39 (REV/ R1)						

TO-39 (REV: R1)

LEAD CODE:

1) Emitter

2) Base

3) Collector

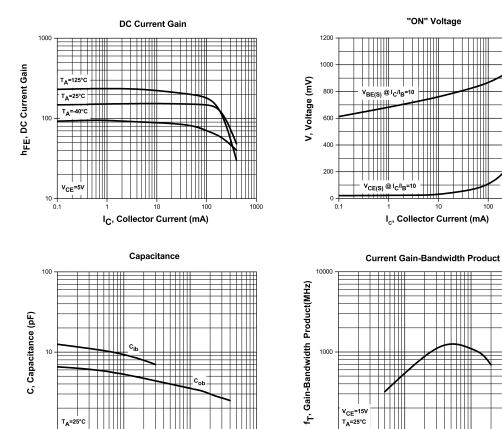
MARKING: FULL PART NUMBER

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SILICON NPN RF TRANSISTOR



100

10

V_R, Reverse Voltage (V)

100

TYPICAL ELECTRICAL CHARACTERISTICS

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1+

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100

10

I_C, Collector Current (mA)

T_A=25°C

1000

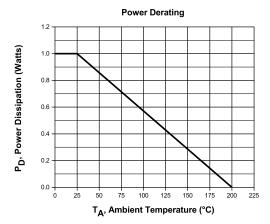
1000



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SILICON NPN RF TRANSISTOR

TYPICAL ELECTRICAL CHARACTERISTICS



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OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- · Environmental regulation compliance
- Customer specific screening
- · Up-screening capabilities

· Custom product packing

Custom bar coding for shipments

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

REQUESTING PRODUCT PLATING

- If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when 1. ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA Main Tel: (631) 435-1110 Main Fax: (631) 435-1824 Support Team Fax: (631) 435-3388 www.centralsemi.com

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